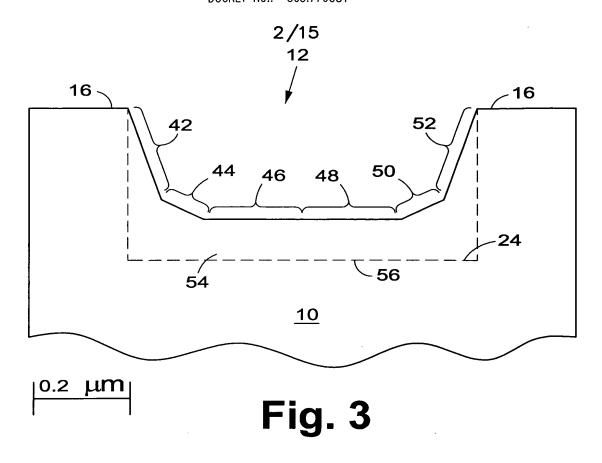
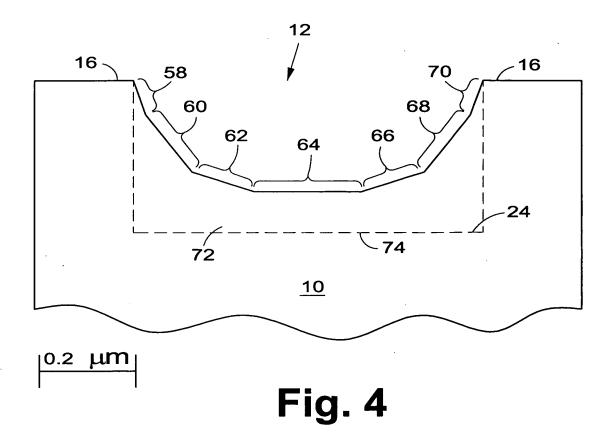
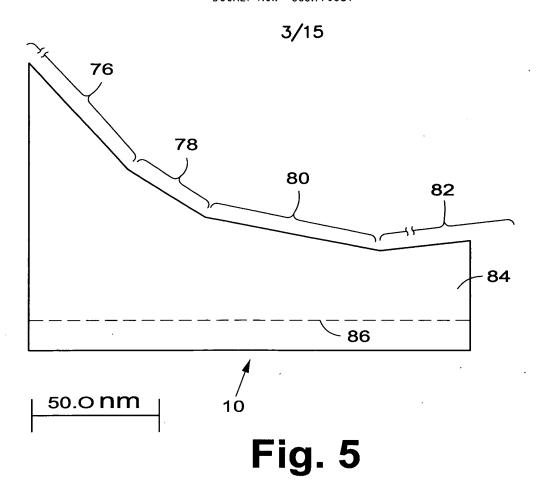


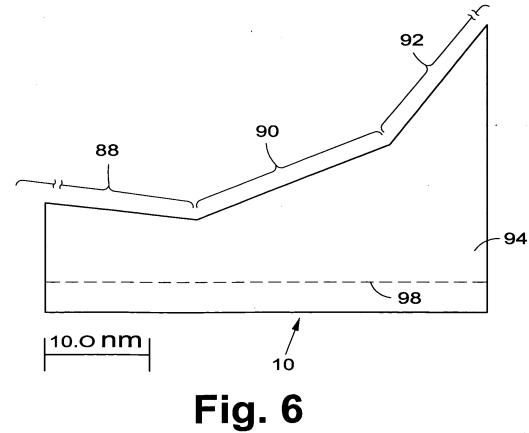
Fig. 2

VERTICAL TRANSISTOR AND METHOD OF MAKII INVENTORS NAME: Fernando Gonzalez DOCKET NO.: 303.776US1

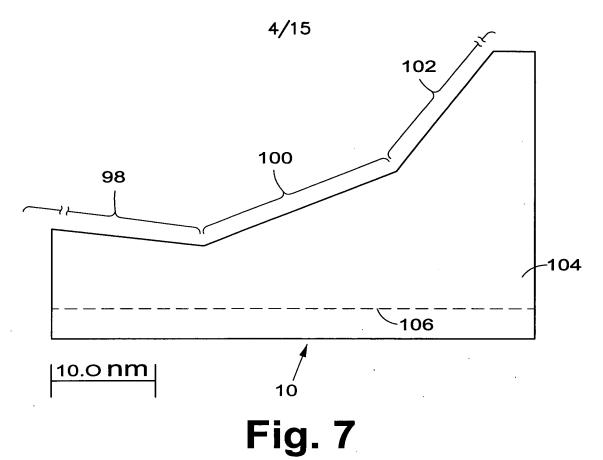












110 108 1112 10.0 nm

Fig. 8



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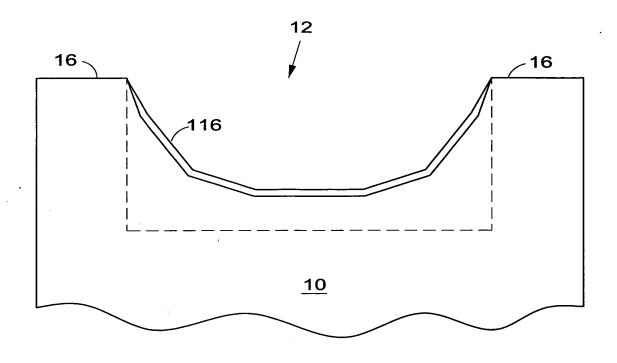
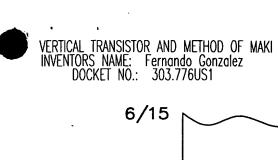
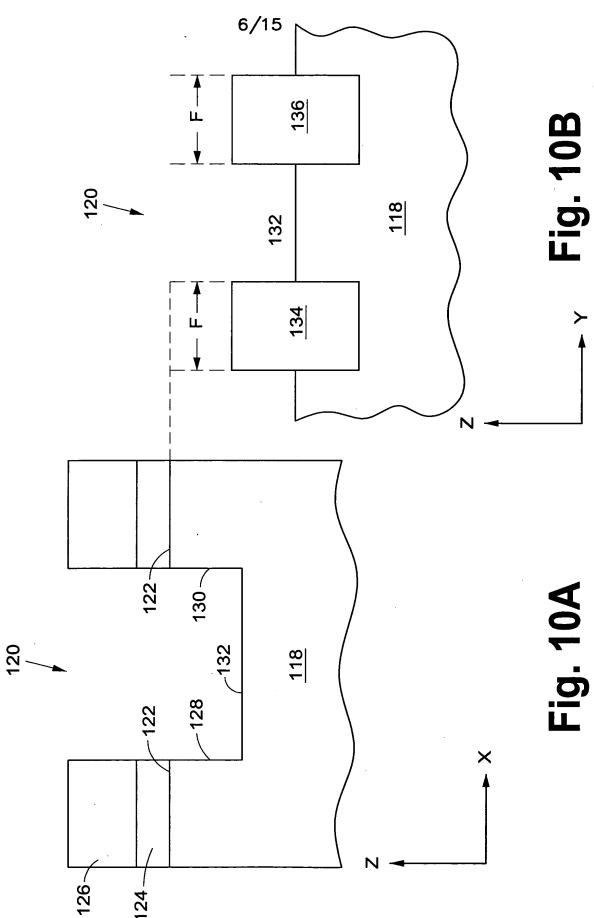
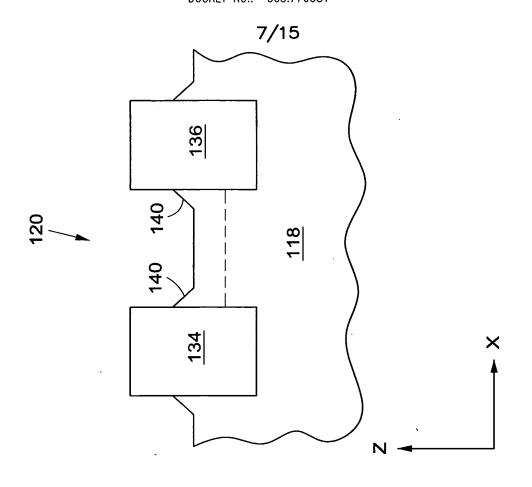


Fig. 9



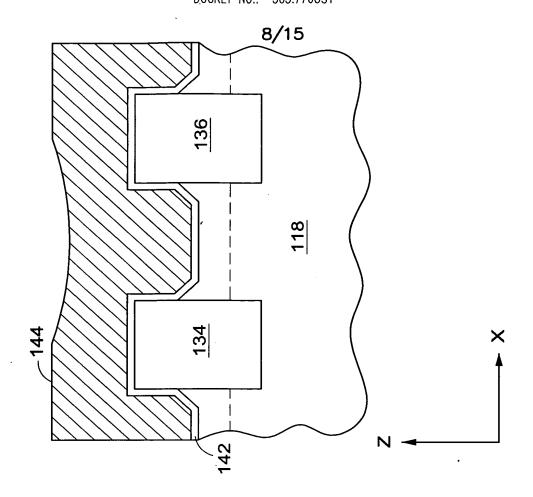


VERTICAL TRANSISTOR AND METHOD OF MAKI INVENTORS NAME: Fernando Gonzalez DOCKET NO.: 303.776US1



120 122 138 118 7

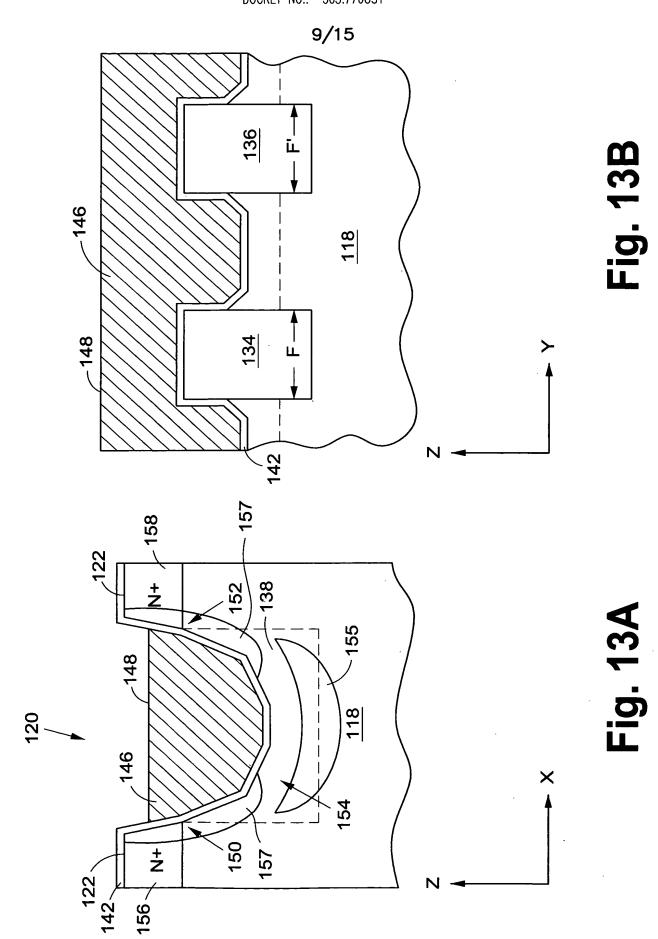
VERTICAL TRANSISTOR AND METHOD OF MAKI INVENTORS NAME: Fernando Gonzalez DOCKET NO.: 303.776US1

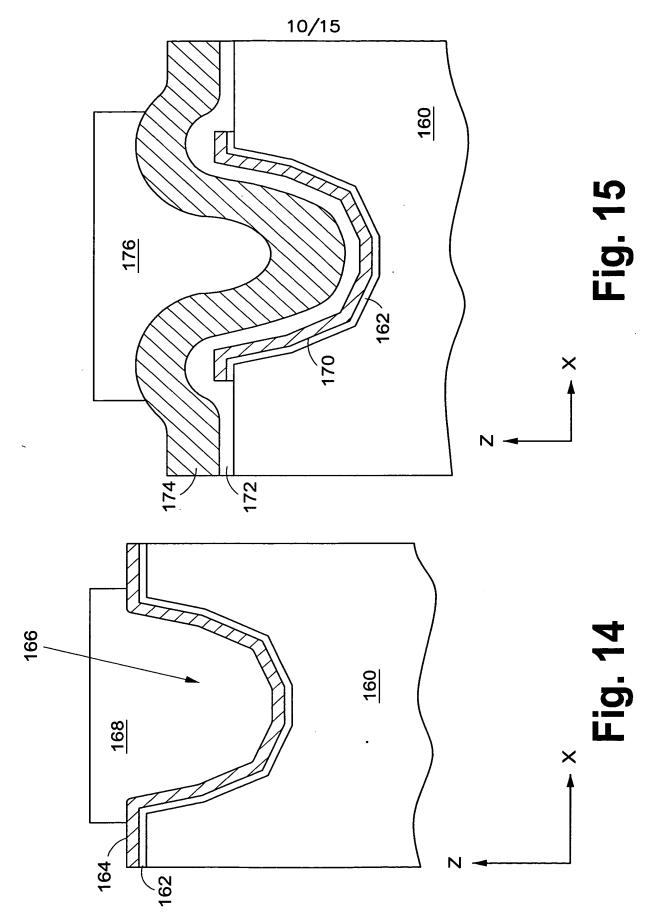


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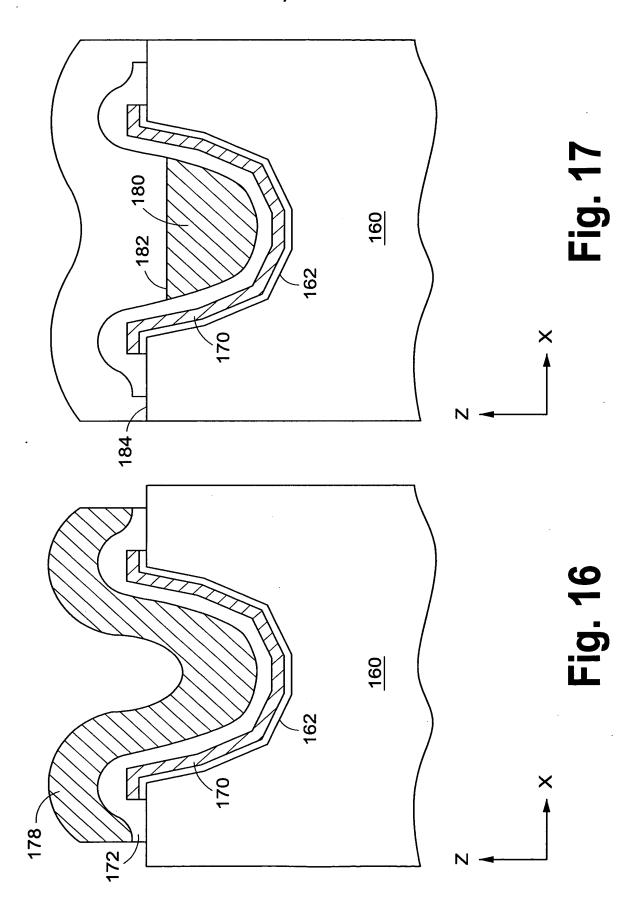
VERTICAL TRANSISTOR AND METHOD OF MAKI INVENTORS NAME: Fernando Gonzalez DOCKET NO.: 303.776US1







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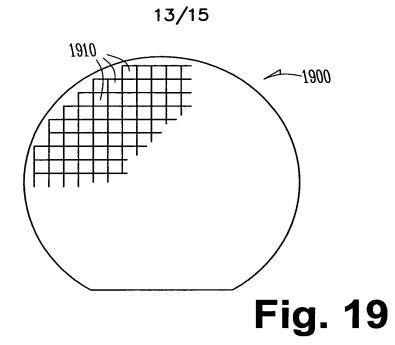
198

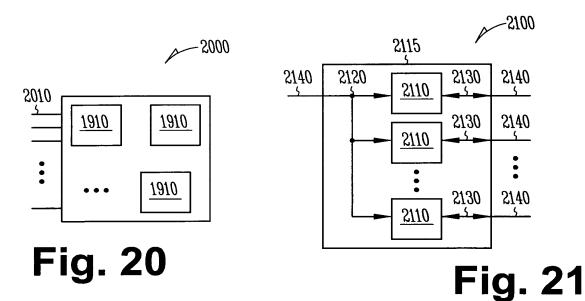


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Fig. 18A







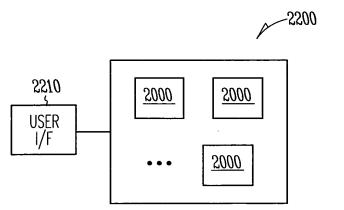
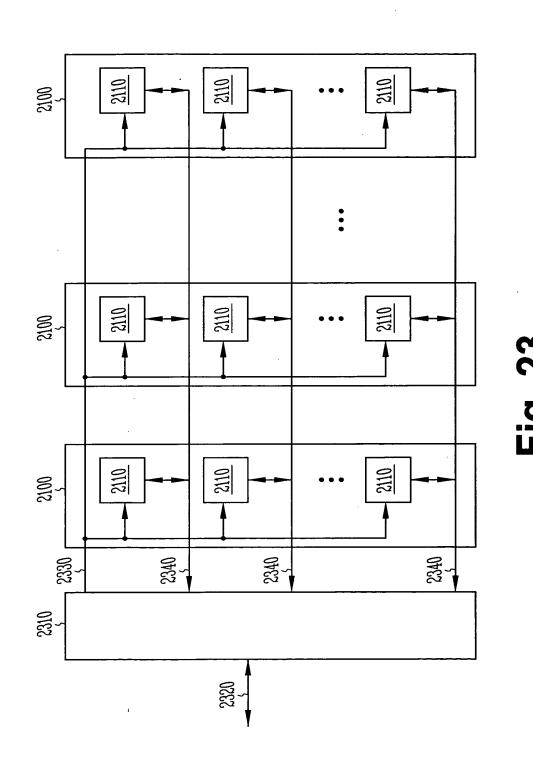


Fig. 22

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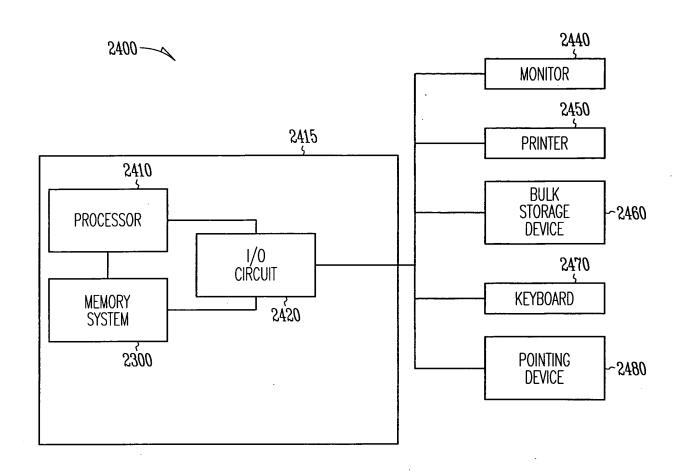


Fig. 24